

Notice of References Cited	Application/Control No. 10/608,620	Applicant(s)/Patent Under Reexamination BOTTNER et al.	
	Examiner Lee, Calvin	Art Unit 2825	Page 1 of 1

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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	A	US-5,578,864	11-1996	Ochi et al.	257/467
*	B	US-2004/0075167	04-2004	Nurnus et al.	257/712
	C	US-			
	D	US-			
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	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
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	O					
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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
*	U	Boikov, Y.A. et al, " Layer by Layer Growth of Bi2Te3 Epitaxial Thermoelectric Heterostructures," 16th International Conference on Thermoelectrics, Dresden, IEEE, August 1997, pp. 89-92
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.